		o. of Questions : 4] SEAT No. :
PA	-1(0203 [Total No. of Pages : 1
		[6010]-76
		B.E. (E & TC) (Insem) NANO ELECTRONICS
	(2	2019 Pattern) (Semester - VIII) (Elective - VI) (404192 B)
		Hour] [Max. Marks : 30 ions to the candidates:
	ucu 1)	Solve Q.1 or Q.2, Q.3 or Q.4.
	2)	Figures to the right indicate full marks.
	3)	Assume suitable data, if necessary.
Q 1)	a)	Explain Electrical conduction and Ohm's Eaw in relation with
,	Í	nanotechnology. [8]
	b)	What are the limitation of silicon material. [7]
		QR
Q2)	a)	Explain what is the role of Molecular recognition in nanotechnology. [7]
	b)	What is polymerization? Explain the process of DNA hybridization with
		schematic. [8]
Q3)	a)	Explain nanoscale lithography. [5]
	b)	With neat diagram explain Nano-CMOS devices. [5]
	c)	Explain principle of operation of AFM techniques. [5]
		OR OR
Q4)	a)	Describe the use of nanoelectronics with suitable example. [5]
	b)	Explain dielectric material for future transistor. [5]
	c)	Discuss nanocrystal non-volatile memories. [5]
		C3C3 8080
		(3(3 8)8)